

Hot Swap Smart Fuse NCP81292

The NCP81292 is a 50 A, electronically re–settable, in–line fuses for use in 12 V, high current applications such as servers, storage and base stations. The NCP81292 offers a very low 0.65 m Ω integrated MOSFET to reduce solution size and minimize power loss. It also integrates a highly accurate current sensor for monitoring and overload protection.

Power Features

- Co-packaged Power Switch, Hotswap Controller and Current Sense
- Up to 50 A Continuous, 80 A Peak Output Current
- Vin Range: 4.5 V to 18 V
- 0.65 mΩ, no R_{SENSE} Required

Control Features

- Enable Input
- Optional Enable-controlled Output Pulldown when Disabled
- Programmable Soft-Start
- Programmable, Multi-level Current Limit

Reporting Features

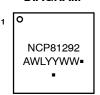
- Accurate Analog Load Current Monitor
- Programmable Over Current Alert Output
- Analog Temperature Output
- Status Fault OK Output

Other Features

- 5 mm x 5 mm QFN32 Package
- Operating Temperature: -40°C to 125°C
- Can be Paralleled for Higher Current Applications
- Built-in Insertion Delay for Hotswap Applications
- Auto-Retry Mode for Following Protection Features
 - Current-limit after Delay
 - ◆ Fast Short-circuit Protection
 - Over-Temperature Shutdown
 - ◆ Excessive Soft-start Duration
- Internal Switch Fault Diagnostics
- Low-power Auxiliary Output Voltage

MARKING DIAGRAM





NCP81292 = Specific Device Code

= Assembly Location

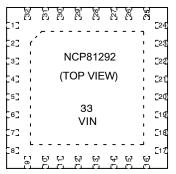
WL = Wafer Lot YY = Year WW = Work Week

= Pb-Free Package

(may or may not be present)

(Note: Microdot may be in either location)

PINOUT



For more details see Figure 1.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

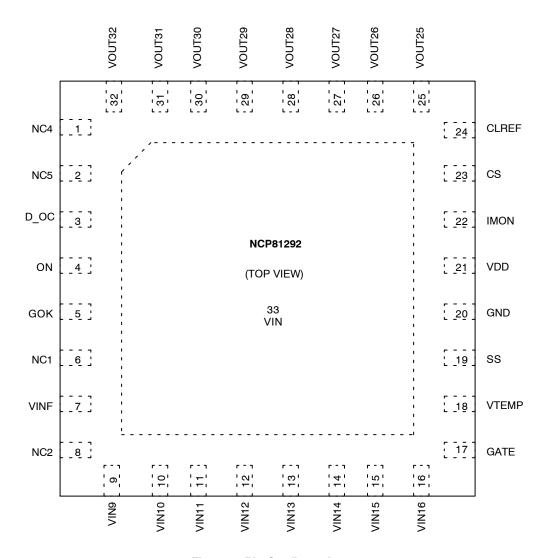


Figure 1. Pin Configuration

Table 1. DEVICE ORDERING INFORMATION

Device	Package	Shipping [†]
NCP81292MNTXG	QFN32	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

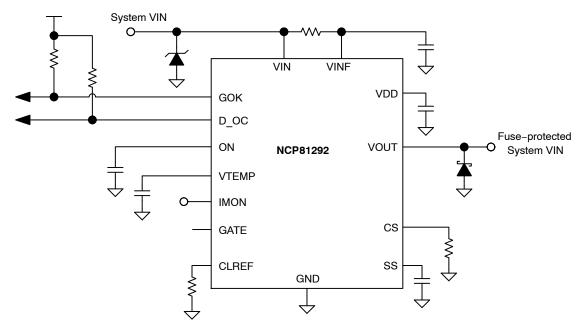


Figure 2. Typical Application

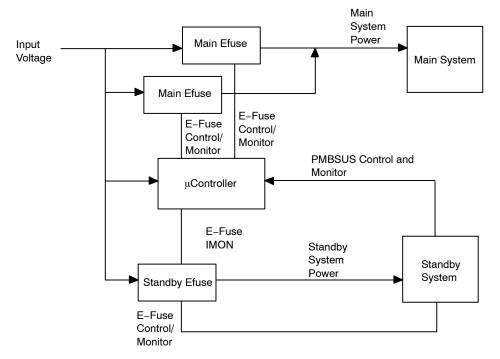


Figure 3. Typical Application Diagram

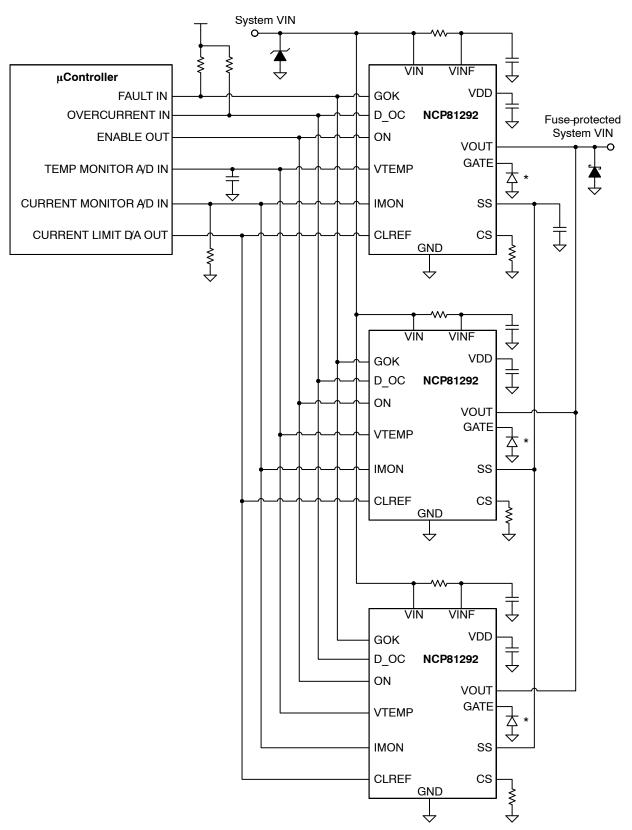


Figure 4. Application Schematic - Parallel Fuse Operation with Controller

^{*}For parallel NCP81292 applications, a BAS16, or equivalent, diode is recommended at each GATE pin to limit the negative voltage/current during output fault conditions. Due to reverse leakage potential, a schottky diode should not be used.

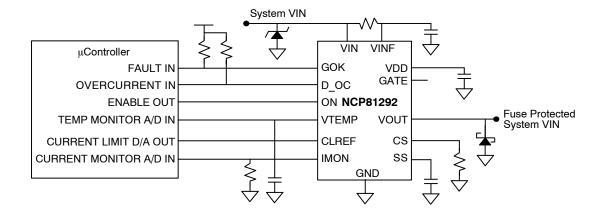


Figure 5. Application Schematic - Single EFuse with Controller

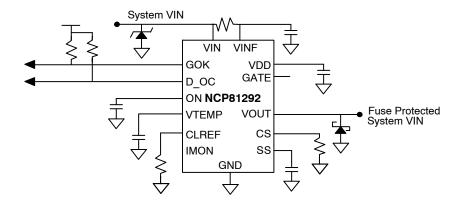


Figure 6. Application Schematic - Stand-alone Single EFuse

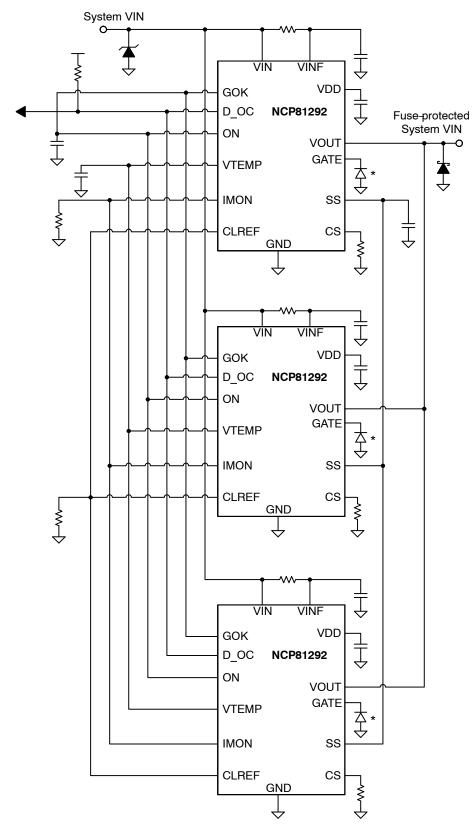


Figure 7. Application Schematic - Stand-alone Parallel EFuse

^{*}For parallel NCP81292 applications, a BAS16, or equivalent, diode is recommended at each GATE pin to limit the negative voltage/current during output fault conditions. Due to reverse leakage potential, schottky diodes should not be used.

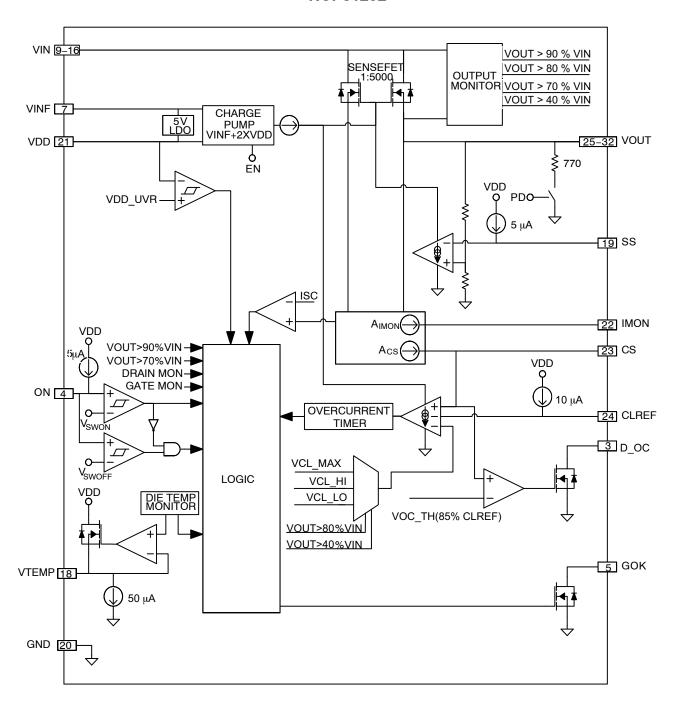


Figure 8. Block Diagram

Table 2. PIN DESCRIPTION

Pin No.	Symbol	Description			
1	NC4	No electrical connection internally. May connect to any potential			
2	NC5	No electrical connection internally. May connect to any potential			
3	D_OC	Overcurrent indicator output (open drain). Low indicates the NCP81292 is limiting current. The D_OC output does not report current limiting during soft–start.			
4	ON	nable input and output pulldown resistance control.			
5	GOK	OK status indicator output (open drain). Low indicates that the NCP81292 was turned off by a fault.			
6	NC1	Test pin. Do not connect to this pin. Leave floating			
7	VINF	Control circuit power supply input. Connect to VIN pins through an RC filter. (1 Ω / 0.1 μ F)			
8	NC2	Internal FET sense pin. Do not connect to this pin. Leave floating			
9	VIN09	Input of high current output switch			
10	VIN10	Input of high current output switch			
11	VIN11	Input of high current output switch			
12	VIN12	Input of high current output switch			
13	VIN13	Input of high current output switch			
14	VIN14	Input of high current output switch			
15	VIN15	Input of high current output switch			
16	VIN16	Input of high current output switch			
17	GATE	Internal FET gate pin. Connect to the cathode of an anode grounded diode such as BAS16P2T5G. A 4.7 nF ceramic capacitor is reserved between this pin and GND for NCP81292 to mitigate the oscillation risk when small amount of output capacitance (< 100 μ F) or long input/output cable (large L _{IN} / L _{OUT}) happens.			
18	VTEMP	Analog temperature monitor output.			
19	SS	Soft Start time programming pin. Connect a capacitor to this pin to set the softstart time.			
20	GND	Ground			
21	VDD	Linear regulator output			
22	IMON	Analog current monitor output			
23	CS	Current sense feedback output (current). Scaling the voltage developed at this pin with a resistor to ground makes this also an input for several current limiting functions and overcurrent indicator D_OC.			
24	CLREF	Current limit setpoint input for normal operation (after soft-start).			
25	VOUT25	Output of high current output switch			
26	VOUT26	Output of high current output switch			
27	VOUT27	Output of high current output switch			
28	VOUT28	Output of high current output switch			
29	VOUT29	Output of high current output switch			
30	VOUT30	Output of high current output switch			
31	VOUT31	Output of high current output switch			
32	VOUT32	Output of high current output switch			
33	VIN33	Input of high current output switch			

Table 3. MAXIMUM RATINGS

Rating		Symbol	Min	Max	Unit
Input Voltage Range	VOUT Enabled	V _{IN} , V _{INF}	-0.3	20	V
(VINx, VINF pins)	VOUT Disabled (Note 2)	1	-0.3	30	V
Output Voltage Range (VOUTx pins)		V _{OUT}	-0.3 -1 (<500 ms)	20	V
VDD Pin Voltage Range		V _{DD}	-0.3	6	V
GATE Pin Voltage Range		V _{GATE}	-0.3, -0.8 (<1 ms)	30	V
		V _{GATE} -V _{OUT}	-20	20	V
All Other Pins (Note 3)			-0.3	V _{DD} + 0.3	V
Operating Junction Tempe	rature Range	T _J	-40	150	°C
Storage Temperature Ran	ge	T _{STG}	-55	150	°C
Lead Soldering Temperatu	re, Reflow, Pb-Free (Note 4)	T _{SLD}		260	°C
Electrostatic Discharge, Human Body Model (per EIA/JESD22-A114)		ESD _{HBM}		3.0	kV
Electrostatic Discharge, Charged Device Model (per EIA/JESD22–A115)		ESD _{CDM}		2.0	kV
Maximum Latch-Up Current Limit (per JESD78)		I _{LU}		100	mA
Moisture Sensitivity Level		MSL	3	3	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. All signals referenced to GND unless noted otherwise.
- 2. Vout disable is the state of output OFF when internal FET has turned off by disable ON or FAULTs protection.
- 3. Pin ratings referenced to VDD apply with VDD at any voltage within the VDD Pin Voltage Range.
- 4. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

Table 4. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient (Note 5)	$R_{ heta JA}$	30	°C/W
Thermal Resistance, Junction-to-Top-Case	$R_{ heta JCT}$	50	°C/W
Thermal Resistance, Junction-to-Bottom-Case	$R_{ heta JCB}$	1.5	°C/W
Thermal Resistance, Junction-to-Board (Note 6)	$R_{ heta JB}$	1.5	°C/W
Thermal Resistance, Junction-to-Case (Note 7)	$R_{ heta JC}$	1.5	°C/W

- R_{θJA} is obtained by simulating the device mounted on a 500 mm², 1-oz Cu pad on a 80 mm x 80 mm, 1.6 mm thick 8-layer FR4 board.
 R_{θJB} value based on hottest board temperature within 1 mm of the package.
- 7. $R_{\theta JC} \approx R_{\theta JCT} /\!\!/ R_{\theta JCB}$ (Two-Resistor Compact Thermal Model, JESD15-3).

Table 5. RECOMMENDED OPERATING RANGES

Parameter (Note 1)	Symbol	Min	Max	Unit
VIN, VINF Pin Voltage Range		4.5	18	V
Maximum Continuous Output Current	I _{AVE}		50	Α
Peak Output Current	I _{PEAK}		80	Α
VDD Output Load Capacitance Range	C _{VDD}	2.2	10	μF
VTEMP Output Load Capacitance Range	C _{VTEMP}	0.1		μF
Softstart Duration	T _{SS}	10	100	ms
CS Load Resistance Range	R _{CS}	1.8	4	kΩ
CLREF Voltage Range	V _{CLREF}	0.2	1.55	V
Operating Junction Temperature	T _{J(OP)}	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 6. ELECTRICAL CHARACTERISTICS (VINx = VINF = 12.0 V, V_{ON} = 3.3 V, C_{VINF} = 0.1 μF, C_{VDD} = 4.7 μF, C_{VTEMP} = 0.1 μF, R_{VTEMP} = 1 kΩ, C_{SS} = 100 nF (unless specified otherwise) Min/Max values are valid for the temperature range −40°C ≤ T_J ≤ 125°C unless noted otherwise, and are guaranteed by design and characterization through statistical correlation.

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
VINF INPUT						
Quiescent Current		V _{ON} > 1.4 V, no load		3.23	5.0	mA
		V _{ON} > 1.4 V, fault			5.0	mA
		V _{ON} < 0.8 V		2.38	4.0	mA
		V _{ON} < 0.8 V, VINF = 16 V			4.0	mA
VDD REGULATOR						
VDD Output Voltage	V _{DD_NL}	I _{VDD} = 0 mA, VINF = 6 V	4.7	5.09	5.3	V
VDD Load Capability	I _{DDLOAD}	VINF = 5.5 V			30	mA
VDD Current Limit	I _{DD_CL}	VINF = 12 V and VINF = 6 V	50	70		mA
VDD Dropout Voltage		I _{VDD} = 25 mA, VINF = 4.5 V		85	200	mV
UVLO threshold – rising	V _{DD_UVR}		4.1	4.3	4.5	V
UVLO threshold – falling	V _{DD_UVF}		3.8	4.0	4.2	V
ON INPUT						
Bias Current	I _{ON}	From pin into a 0 V or 1.5 V source	4.0	5.0	6.0	μΑ
Switch ON Threshold	V _{SWON}		1.33	1.4	1.47	V
Switch OFF/ Pulldown Upper Threshold	V _{SWOFF}		1.13	1.2	1.27	V
Pulldown Lower Threshold	V _{PDOFF}			0.8		V
Switch ON Delay Timer	t _{ON}	From ON transitioning above V _{SWON} to SS start	0.6	1.0	2.5	ms
Switch OFF Delay Time (Note 8)	t _{OFF}	From ON transitioning below V _{SWOFF} to GATE pulldown		1.7		μs
ON Current Source Clamp Voltage	V _{ON_CLMP}	Max pullup voltage of current source	2.8	3.0		V
Load Pulldown Delay Timer	t _{PD_DEL}	From ON transitioning into the range between V _{SWOFF} and V _{PDOFF}		2.0		ms
Output Pulldown Resistance	R _{PD}	V _{OUT} = 12 V, PD mode = 1		0.77		kΩ
SS PIN	•		•		•	
Bias Current	I _{SS}	From pin into a 0 V or 1 V source	4.62	5.15	5.62	μΑ
Gain to VOUT	AV _{SS}		9.6	10	10.4	V/V
SS Pulldown Voltage	V _{OL_SS}	0.1 mA into pin during ON delay		22		mV
GOK OUTPUT						
Output Low Voltage	V _{OL_GOK}	I _{GOK} = 1 mA			0.1	V
Off-state Leakage Current	I _{LK_GOK}	V _{GOK} = 5 V			1.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

8. Guaranteed by design or characterization data. Not tested in production.

Table 6. ELECTRICAL CHARACTERISTICS (VINx = VINF = 12.0 V, V_{ON} = 3.3 V, C_{VINF} = 0.1 μF, C_{VDD} = 4.7 μF, C_{VTEMP} = 0.1 μF, R_{VTEMP} = 1 kΩ, C_{SS} = 100 nF (unless specified otherwise) Min/Max values are valid for the temperature range −40°C ≤ T_J ≤ 125°C unless noted otherwise, and are guaranteed by design and characterization through statistical correlation.

Parameter	Symbol	Test Conditions		Min	Тур	Max	Units
IMON/CS OUTPUT				•			•
IMON or CS Current	I _{IMON} /I _{CS}	T _J = 0 to 125°C	IOUT = 5 A (Note 8)		50		μА
(single EFuse) Based on 10 μA/A			IOUT = 10 A (Note 8)		100		μΑ
			IOUT = 25 A (Note 8)		250		μΑ
			IOUT = 50 A (Note 8)		500		μΑ
Accuracy (single EFuse)		T _A = 25°C	IOUT = 8 A	-3		3	%
			IOUT > 8 A (Note 8)	-3		3	%
		T _A = 0 to 85°C	IOUT ≥ 8 A (Note 8)	-5		5	%
IMON or CS Current Source Clamp Voltage	V _{IM_CLMP} / V _{CS_CLMP}	Max pullup voltage	e of current source	2.8	3.0		V
CURRENT LIMIT & CLREF P	IN						
Current Limit Voltage	V _{CL_TH}	If V _{CS} > VCL_TH current limiting regulation occurs via gate		95	98	101	%V _{CLREF}
Current Limit Enact Offset Voltage	V _{ENACT}	0.2 V < V _{CLREF} < 1	0.2 V < V _{CLREF} < 1.55 V		-24	12	mV
Current Limit Clamp Voltage	V _{CL_LO}	VOUT < 40% VIN, V _{CLREF} > 0.165 V		135	152	165	mV
	V _{CL_HI}	40% VIN < VOUT < 80% VIN V _{CLREF} > 0.55 V		480	504	520	mV
Max Current Limit Reference Voltage	V _{CL_MX}	VOUT > 80% VIN, V _{CLREF} > 1.65 V		1.55	1.6	1.65	V
Response Time (Note 8)	t _{CL_REG}	V _{CS} > V _{CLREF} curr	rent limiting time		200		μs
CLREF Bias Current	I _{CL}	From pin into a 1.2	2 V source	9.6	10	10.4	μΑ
CLREF Current Source Clamp Voltage	V _{CL_CLMP}	Max pullup voltage	of current source	2.8	3.0		V
FET Turn-off Timer	t _{CL_LA}	Delay between current limit detection and FET turn-off (GOK = 0)			250		μs
D_OC OUTPUT		•					
Overcurrent Threshold	VOC_TH	If V _{CS} > VOC_TH, the D_OC pin pulls low		82	85	89	%V _{CLREF}
Output Low Voltage	V _{OL_DOC}	I _{DOC} = 1 mA				0.1	V
Off-state Leakage Current	I _{LK_DOC}	V _{DOC} = 5 V				1.0	μΑ
De-bounce Time (Note 8)		V _{CS} < limit until D_	OC rising		3.0		μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} Guaranteed by design or characterization data. Not tested in production.

Table 6. ELECTRICAL CHARACTERISTICS (VINx = VINF = 12.0 V, V_{ON} = 3.3 V, C_{VINF} = 0.1 μF, C_{VDD} = 4.7 μF, C_{VTEMP} = 0.1 μF, R_{VTEMP} = 1 kΩ, R_{VTEMP} = 1 kΩ, R_{VTEMP} = 1 kΩ, R_{VTEMP} = 100 nF (unless specified otherwise) Min/Max values are valid for the temperature range R_{VTEMP} = 125°C unless noted otherwise, and are guaranteed by design and characterization through statistical correlation.

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
SHORT CIRCUIT PROTECTI	ON			•		
Current Threshold (Note 8)	I _{SC}			100		Α
Response Time (Note 8)	t _{SC}	From I _{OUT} > I _{LIMSC} until gate pulldown		500		ns
VTEMP OUTPUT			•			
Bias Voltage	V _{VTEMP25}	At 25°C		450		mV
Gain (Note 8)	A _V TEMP	$0^{\circ}\text{C} \leq \text{T}_{\text{J}} \leq 125^{\circ}\text{C}$		10		mV/°C
Load Capability (Note 8)	R _V TEMP	At 25°C		1		kΩ
Pulldown Current	I _V TEMP	At 25°C		50		μΑ
THERMAL SHUTDOWN						
Temperature Shutdown (Note 8)	T _{TSD}	GOK pulls down		140		°C
OUTPUT SWITCH (FET)	•					
On Resistance	R _{DSon}	T _J = 25°C, I _{OUT} = 8 A		0.65	1.0	mΩ
Off-state leakage current	I _{DSoff}	VIN = 16 V, V _{ON} < 1.2 V, T _J = 25°C			1.0	μΑ
FAULT detection						
V _{DS} Short Threshold	VDS_TH	Startup postponed if VOUT > VDS_TH at V _{ON} > V _{SWON} transition		88.8		%VIN
V _{DS} Short OK Threshold	VDS_OK	Startup resumed if VOUT < VDS_OK anytime after postponed	68.6			%VIN
V _{GD} Short Threshold	VDG_TH	Startup postponed if $V_G > VDG_TH$ at $V_{ON} > V_{SWON}$ transition		3.1		V
V _{GD} Short OK Threshold	VDG_OK	Startup resumed if $V_G < VDG_OK$ anytime after postponed		3.0		V
V _G Low Threshold	VG_TH	Latch/Restart if V _{GD} < VG_TH after t _{SSF_END} or t _{GATE_FLT}		5.4		V
V _{OUT} Low Threshold	V _{OUTL_TH}	Latch/Restart if V _{OUT} < VOUTL_TH after 90 tssr_end 90			%VIN	
Gate Fault Timer (Note 8)	tgate_flt				ms	
Startup Timer Failsafe (Note 8)	t _{SSF_END}	Time from V _{ON} > V _{SWON} transition, Max programmable softstart time		200		ms
AUTO-RETRY			ı	ı l		<u> </u>
Auto-Retry Delay	t _{DLY} RETRY	Delay from power-down to retry of startup		1000		ms

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{8.} Guaranteed by design or characterization data. Not tested in production.

TYPICAL CHARACTERISTICS

Test Conditions: Vin = 12 V, Rcs = 2 k Ω , Css = 200 nF, R_{CLREF} = 121 k Ω , R_{IMON} = 2 k Ω , T_A = 25°C, unless otherwise specified.

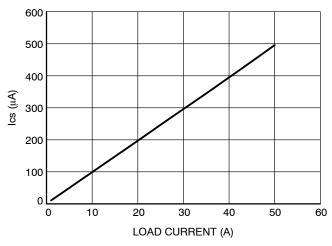
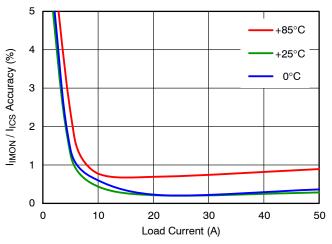


Figure 9. Ics vs. Load Current

Figure 10. Imon vs. Load Current



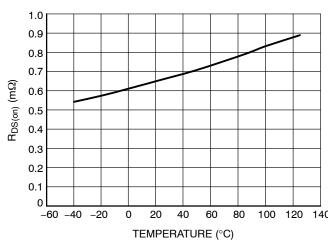


Figure 11. I_{IMON}/ I_{CS} Accuracy vs. Load Current

Figure 12. Output Switch $R_{DS(on)}$ @ 22 A vs. Temperature

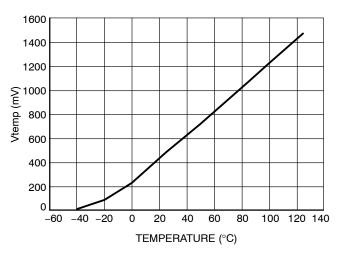


Figure 13. Vtemp vs. Temperature (no load)

TYPICAL CHARACTERISTICS

Test Conditions: Vin = 12 V, Rcs = 2 k Ω , Css = 200 nF, R_{CLREF} = 121 k Ω , R_{IMON} = 2 k Ω , T_A = 25°C, unless otherwise specified.

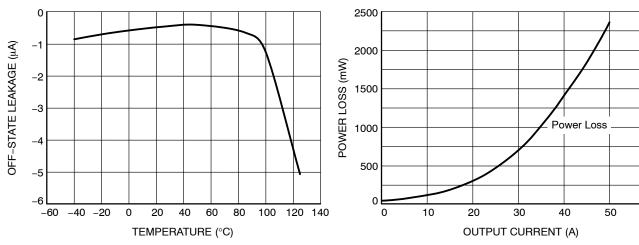


Figure 14. Output Switch Off-state Leakage vs. Temperature

Figure 15. Power Loss vs. Load Current

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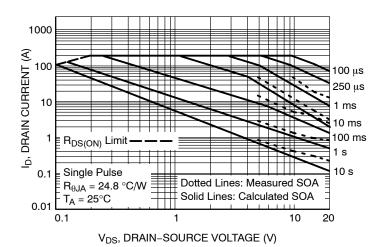


Figure 16. Internal FET's Safe Operating Area (SOA)

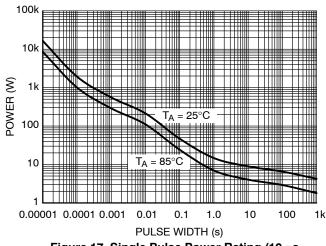


Figure 17. Single Pulse Power Rating (10 μ s – 1000 s, Junction–to–Ambient, Note 4)

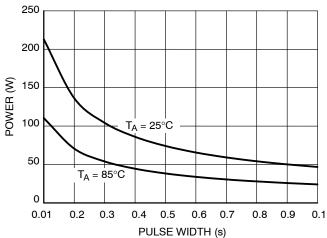


Figure 18. Single Pulse Power Rating (10 ms – 100 ms, Junction-to-Ambient, Note 4)

TYPICAL CHARACTERISTICS

Test Conditions: Vin = 12 V, Rcs = 2 k Ω , Css = 200 nF, R_{CLREF} = 121 k Ω , R_{IMON} = 2 k Ω , T_A = 25°C, unless otherwise specified.

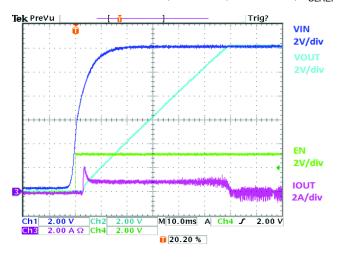


Figure 19. Start Up by VIN (lout = 0 A)

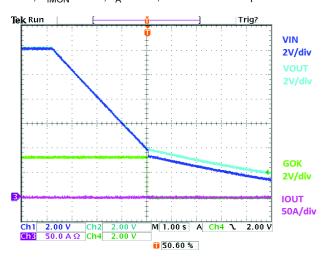


Figure 20. Shut Down by VIN (lout = 0 A)

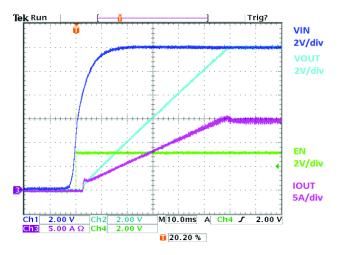


Figure 21. Start Up by VIN (lout = 15 A)

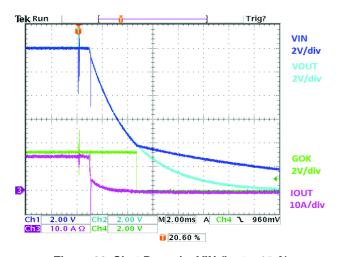


Figure 22. Shut Down by VIN (lout = 15 A)

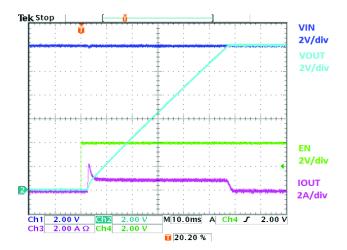


Figure 23. Start Up by EN (lout = 0 A)

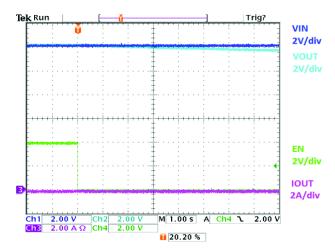
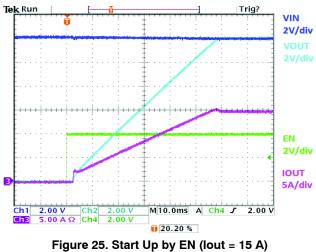
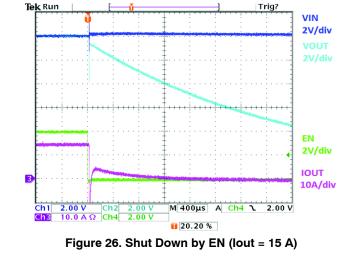


Figure 24. Shut Down by EN (lout = 0 A)

TYPICAL CHARACTERISTICS

Test Conditions: Vin = 12 V, Rcs = 2 k Ω , Css = 200 nF, R_{CLREF} = 121 k Ω , R_{IMON} = 2 k Ω , T_A = 25°C, unless otherwise specified.





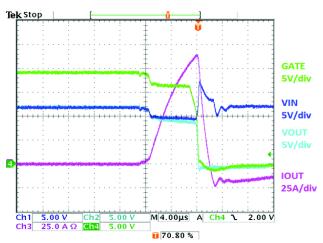


Figure 27. Short Circuit during Normal Operation (lout = 0 A)

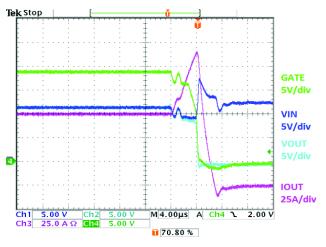


Figure 28. Short Circuit during Normal Operation (lout = 50 A)

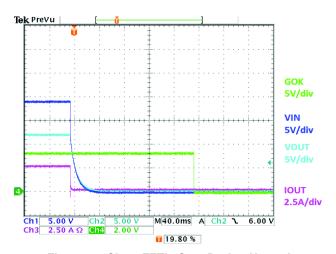


Figure 29. Short FET's Gate During Normal Operation (lout = 2.5 A)

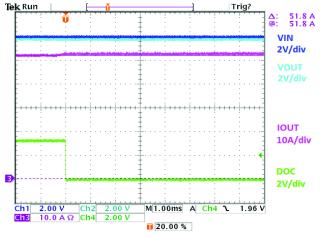
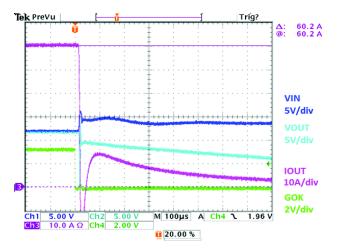


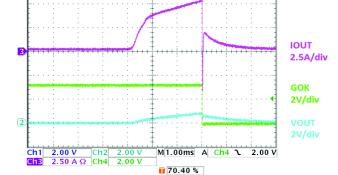
Figure 30. DOC Index for Current Limit during Normal Operation (lout = 51.8 A)

TYPICAL CHARACTERISTICS

Test Conditions: Vin = 12 V, Rcs = 2 k Ω , Css = 200 nF, R_{CLREF} = 121 k Ω , R_{IMON} = 2 k Ω , T_A = 25°C, unless otherwise specified.

Tek Run





VIN 2V/div

Figure 31. OCP during Normal Operation(lout=60.2A)

Figure 32. OCP during Power Up by Enable

General Information

The NCP81292 is an N-channel MOSFET co-packaged with a smart hotswap controller. It is suited for high-side current limiting and fusing in hot-swap applications. It can be used either alone, or in a paralell configuration for higher current applications.

VDD Output (Auxiliary Regulated Supply)

An internal linear regulator draws current from the VINF pin to produce and regulate voltage at the VDD pin. This auxiliary output supply is current–limited to I_{DD_CL} . A ceramic capacitor in the range of 2.2 μF to 10 μF must be placed between the VDD and GND pins, as close to the NCP81292 as possible. The voltage difference between VIN and VINF pin voltage should be within 0.4 V for better CS/IMON performance. Small time constant R/C filter such as 1 $\Omega/0.1~\mu F$ on the VINF pin is recommended.

ON Input (Device Enable)

When the ON pin voltage (V_{ON}) is higher than V_{SWON} , and no undervoltage (UVLO) or output switch faults are present, the output switch turns on. When V_{ON} is lower than V_{SWOFF} , the output switch is off. If V_{ON} is between V_{PDOFF} and V_{SWOFF} for longer than t_{PD_DEL} , the output switches off, and a pulldown resistance to ground, of R_{PD} , is applied to VOUT. In other words, there is behavior as follows:

- When $V_{ON} < 0.8 \text{ V}$, FET turns off.
- When 0.8 V < V_{ON} < 1.2 V, VOUT will discharge with \sim 15 mA.
- When $V_{ON} > 1.2 \text{ V}$, FET turns on.

For standalone applications, the ON pin sources current I_{ON}, which can be used to delay output switch turn-on for some time after the appearance of input voltage by connecting a capacitor from the ON pin to ground.

A bi-level control signal driving to ground can be biased up with a resistive divider to produce ON input levels between $V_{PDOFF} < V_{ON} < V_{SWON}$ and $V_{ON} > V_{SWON}$ in order to always apply the output pulldown when the output switch is off.

SS Output (Soft-Start)

When the output switch first turns on, it does so in a controlled manner. The output voltage (VOUT) follows the voltage at the SS pin, produced by current I_{SS} into a capacitor from SS to ground. The duration of soft-start can be programmed by selection of the capacitor value. In parallel fuse applications, the SS pins of all fuses should be shorted together to one shared SS capacitor. Internal soft-start load balancing circuity will ensure the soft-start current is shared between paralleled devices, so as not to stress one device more than another or hit a soft start-current limit.

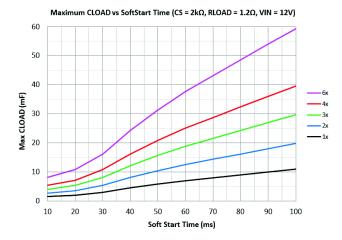
The soft-start capacitor value can be calculated by:

 C_{SS} = (t_{SS} * I_{SS} * AV_{SS})/VIN (where t_{SS} is the target soft–start time). The recommended range of t_{SS} is 10 – 100 ms.

The typical C_{SS} values for different t_{SS} are listed below:

t _{SS} (ms)	C _{SS} (nF)	t _{SS} (ms)	C _{SS} (nF)
10	47	60	270
20	82	70	330
30	120	80	330
40	180	90	470
50	220	100	470

The maximum load capacitor value NCP81292 can power up depends on the device soft–start time. When V_{IN} = 12 V, R_{CS} = 2 k Ω , R_{LOAD} = 2.4 Ω , their relationship for different paralleled operations are shown as below chart (above line device shuts down safely due to protection, below line device powers up successfully without trigger protection):



GOK Output (Gate OK)

The GOK pin is an open-drain output that is pulled low to report the fault under the following conditions:

- V_{DD} voltage is below UVLO voltage at any time.
- V_{ON} disabled and V_{DS_OK} is false (indicates a short from VIN to VOUT).
- V_{ON} disabled and V_{DG_OK} is false (indicates a short from GATE to VIN).
- V_{ON} enabled and V_{SS_OK} is false at t_{SSF_END} (indicates VOUT < 90% after soft–start completes).
- V_{ON} enabled and V_G is below V_{G_TH} at t_{SSF_END} (indicates leakage on GATE in startup).
- V_{ON} enabled and V_G is below V_{G_TH} after t_{GATE_FLT} (indicates leakage on GATE during normal operation).
- $\bullet~V_{ON}$ enabled and a current–limiting condition lasts longer than $t_{OC~LA}$
- V_{ON} enabled and device temperature is above T_{TSD} (indicates an over-temperature is detected).

Usually GOK can't be used as power good to indicate the output voltage is in the normal range.

IMON Output (Current Monitor)

The IMON pin sources a current that is A_{IMON} (10 μ A/A) times the VOUT output current. A resistor connected from the IMON pin to ground can be used to monitor current information as a voltage up to V_{IM_CLMP} . A capacitor of any value in parallel with the IMON resistor can be used to low–pass filter the IMON signal without affecting any internal operation of the device.

CLREF Pin (Current Limit and Over-Current Reference)

The CLREF pin voltage determines the current-limit regulation point and over-current indication point via its interaction with the CS pin voltage. The CLREF voltage can be applied by an external source, such as a hot-swap controller or D-to-A converter, or developed across a programming resistor to ground by the CLREF bias current, I_{CL}. The recommended range of CLREF voltage is 0.2 – 1.55 V.

CS Input/Output (Current Set)

The CS pin is both an input and an output. The CS pin sources a current that is A_{CS} (10 $\mu A/A$) times the VOUT current. This produces a voltage on the CS pin that is the product of the CS pin current and an external CS pin resistance to ground.

The voltage generated on V_{CS} determines the D_OC over-current indicator trip point and the current-limit regulation point, via its interaction with the voltage on CLREF pin.

When the voltage on the CS pin is higher than V_{OC_TH} , D_OC is pulled low. If the CS pin voltage drops below V_{OC_TH} , the D_OC pin is released to and gets pulled high by the external pullup resistor. D_OC transitions based on the following formula:

$$I_{OUT} = \frac{\frac{V_{OC_TH} + V_{ENACT}}{R_{CS}}}{10 \ \mu}$$
 (eq. 1)

The V_{OC_TH} trip point is based on a percentage of V_{CLREF} (86%).

During normal operation ($V_{ON} > V_{SWON}$ for longer than t_{SS_END}), if the voltage on the CS pin is above V_{CL_TH} (V_{CL_TH} is clamped at V_{CL_MX} if $V_{CL_TH} > V_{CL_MX}$), then the gate voltage of the FET is modulated to limit current into the output based on the following formula:

$$I_{OUT} = \frac{\frac{V_{CL_TH} + V_{ENACT}}{R_{CS}}}{10 \ \mu}$$
 (eq. 2)

The V_{CL} _{TH} regulation point is equal to V_{CLREF}.

During startup ($V_{ON} > V_{SWON}$ for less than t_{SS_END}), the current limit reference voltage is clamped according to the following:

- When VOUT < 40% of VIN, V_{CL_TH} = V_{CL_LO} or V_{CLREF} (whichever is lower).
- When VOUT is between 40% and 80% of VIN,
 V_{CL TH} = V_{CL HI} or V_{CLREF} (whichever is lower).
- When VOUT exceeds 80% of VIN, V_{CL_TH} = V_{CL_MX} or V_{CLREF} (whichever is lower).

During soft–start, current is actively limited to V_{CL_TH} for up to t_{CL_REG} before the device shuts off and automatically restarts. Once t_{SS_END} elapses, current exceeding the limit established by V_{CLREF} for > t_{CL_LA} results in device shutdown and automatic restart.

The CS pin must have no capacitive loading other than parasitic device/board capacitance to function correctly. The recommended range of R_{CS} is $1.8-4~\mathrm{k}\Omega$.

CS AMP

NCP81292 uses an auto-zero Op-Amp to sense current in FET with high-accuracy. The internal IMON and CS current source follow below relationship:

$$I_{OUT} = \frac{I_{CS}}{10 \,\mu} \tag{eq. 3}$$

and

$$I_{OUT} = \frac{I_{MON}}{10 \, \mu} \tag{eq. 4}$$

D_OC Output (Over-current Indicator)

The D_OC pin is an open-drain output that indicates when an over-current condition exists after soft-start is complete. When the voltage on the CS pin is higher than V_{OC_TH} , D_OC is pulled low. If output current drops below V_{OC_TH} , the D_OC pin is released and gets pulled high by an external pullup resistor.

VTEMP Output (Temperature Indicator)

VTEMP is a voltage output proportional to device temperature, with an offset voltage. The VTEMP output can source much more current than it can sink, so that if multiple VTEMP outputs are connected together, the voltage of all VTEMP outputs will be driven to the voltage produced by the hottest NCP81292. A 100 nF capacitor or greater must be connected from the VTEMP pin to ground.

Auto-Retry Restart

Under certain fault conditions, the FET is turned off and another soft-start procedure takes place. Between the fault and the new soft-start, there is a delay of t_{DLY_RETRY}. The protection features that use this hiccup mode restart are:

- Over-Current
- Short-Circuit Detection
- Over-Temperature
- Excessive Soft-Start Duration
- Gate Leakage

Protection Features

For the following protection features, the FET turns off and initiates a restart, unless noted otherwise.

Excessive Current Limiting

If a current limiting condition exists anytime for a continuous duration > $t_{\rm CL}$ LA, then the FET restarts.

Excessive Soft-Start Duration

During soft–start, current is actively limited to V_{CL_TH} for up to t_{CL_REG} before the device shuts off and automatically restarts. Once t_{SS_END} elapses, current exceeding the limit established by V_{CLREF} for > t_{CL_LA} results in device shutdown and automatic restart.

Short Circuit Detection

If switch current exceeds I_{SC} , the device reacts within t_{SC} , and the FET restarts. The short–circuit current monitor is independent of CS, CLREF, IMON and current limit setting (cannot be changed externally).

Over-Temperature Shutdown

If the FET controller temperature > T_{TSD} , then the FET restarts.

FET Fault Detection

The device contains various FET monitoring circuits:

- VIN to VOUT short: If the device is disabled and VOUT > V_{DS_TH} then GOK is pulled low and the device is prevented from powering up. The device is allowed to power up once VOUT < V_{DS_OK}.
- GATE to VIN short: If the device is disabled and GATE (Pin 8) > V_{DG_TH}, then GOK is pulled low and device is prevented from powering up. The device allowed to power up once GATE < V_{DG_OK}.
- GATE leakage startup.
 If (GATE VINF) < V_{G_TH} at t_{SSF_END}, then GOK is pulled low and FET restarts.
- GATE leakage normal operation.
 If (GATE VINF) < V_{G_TH} for t_{GATE_FLT} time after the soft–start timer completes, then GOK is pulled low and device restarts.

FET SOA Limits

In-built timed current limits and fault-monitoring circuits ensure the co-packaged FET is always kept within SOA limits.

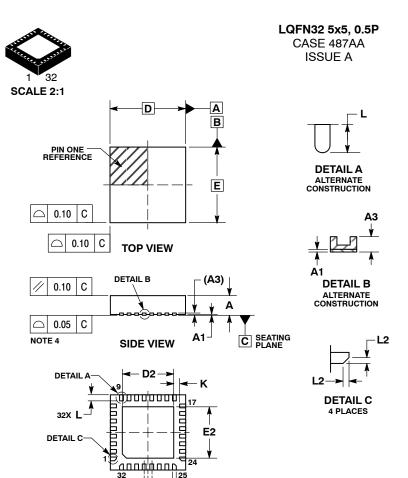
The NCP81292 is rated for 50 A continuous current. For repetitive pulsed loads up to 80 A with a period less than 200 ms, 50 A RMS is supported.

Multiple Fuse Power Up

When multiple NPC81292 are paralleled together as shown in Figure 4, they will turn on together. Keeping the current through each switch within 1 A (typical) helps to prevent overstress on each switching during soft–start.

For stand-alone parallel applications, the ON and GOK pins should be connected as shown in Figure 7 to synchronize hiccup timing and prevent cascading faults.

When using system μ Controller for parallel applications (Figure 4), the μ Controller should be provisioned such that ON is not asserted until GOK is released to high state.



DATE 03 OCT 2017

NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED
 TERMINAL AND IS MEASURED BETWEEN
 O 15 AND 0 30 MM EPOM THE TERMINAL TIE
- 0.15 AND 0.30 MM FROM THE TERMINAL TIP.
 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS					
DIM	MIN	MAX				
Α	1.20	1.40				
A1	-	0.05				
А3	0.20	REF				
b	0.18	0.30				
D	5.00	BSC				
D2	3.30	3.50				
E	5.00	BSC				
E2	3.30	3.50				
е	0.50	BSC				
L	0.30	0.50				
L2	0.13	0.13 REF				

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

A = Assembly Location WL = Wafer Lot

YY = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDERING FOOTPRINT*

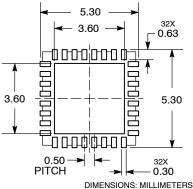
BOTTOM VIEW

0.10 M C A B

0.05 M C NOTE 3

е

e/2



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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